

Vishay Semiconductors

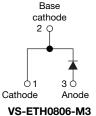
Hyperfast Rectifier, 8 A FRED Pt®

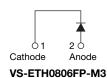




2L TO-220AC

2L TO-220 FULL-PAK

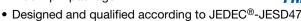




PRODUCT SUMMARY				
Package	2L TO-220AC, 2L TO-220FP			
I _{F(AV)}	8 A			
V_{R}	600 V			
V _F at I _F	2.65 V			
t _{rr} (typ.)	16 ns			
T _J max.	175 °C			
Diode variation	Single die			

FEATURES

- · Hyperfast soft recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- True 2 pin package



• Material categorization: For definitions of compliance please see www.vishay.com/doc?99912





COMPLIANT HALOGEN FREE

DESCRIPTION/APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V _{RRM}		600	V	
Average rectified femiliary automatica DC		T _C = 146 °C	8	А	
Average rectified forward current in DC FULL-I	PAK I _{F(AV)}	T _C = 114 °C	°		
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	80		
Repetitive peak surge current		T _C = 137 °C	16	۸	
Square wave 20 kHz duty cycle (50 %) FULL-I	PAK	T _C = 96 °C	16	Α	
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to 175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	600	-	-	
Forward voltage	V	I _F = 8 A	-	2.0	2.65 V	
	V _F	I _F = 8 A, T _J = 150 °C	-	1.3	1.85	
Reverse leakage current I _R		$V_R = V_R$ rated	-	0.02	12	
		T _J = 150 °C, V _R = V _R rated	-	15	100	μA
Junction capacitance	C _T	V _R = 600 V	-	6	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH



VS-ETH0806-M3, VS-ETH0806FP-M3

Vishay Semiconductors

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, dI_F/dt = 10$	00 A/μs, V _R = 30 V	-	16	23	
Payaraa raaayan, tima		$I_F = 8 \text{ A}, dI_F/dt = 10$	00 A/μs, V _R = 30 V	-	20	28	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	21	-	ns
		T _J = 125 °C	I _F = 8 A dI _F /dt = 200 A/μs V _B = 390 V	-	39	-	
Parl man and	1	T _J = 25 °C		-	3	-	Α
Peak recovery current	IRRM	T _J = 125 °C		-	5	-	A
Daviawaa waaayawy ahayaa		T _J = 25 °C		-	36	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	108	-	nc
Reverse recovery time	t _{rr}		I _F = 8 A	-	30	-	ns
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 600 A/μs	-	13	-	Α
Reverse recovery charge	Q _{rr}	V _R = 390 V	-	205	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance,	D		ı	2.0	2.6		
junction to case FULL-PAK	R_{thJC}		-	4.6	5.5		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
\A/-:			-	2	-	g	
Weight			i	0.07	-	OZ.	
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)	
Marking davis		Case style 2L TO-220AC	ETH0806				
Marking device		Case style 2L TO-220 FULL-PAK		ETH0	806FP		

Vishay Semiconductors

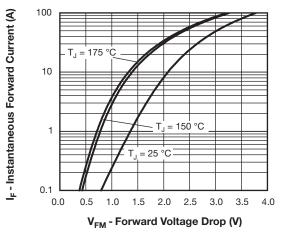


Fig. 1 - Typical Forward Voltage Drop Characteristics

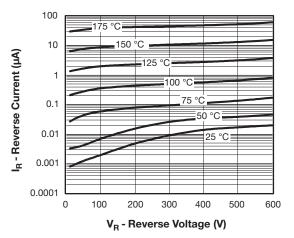


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

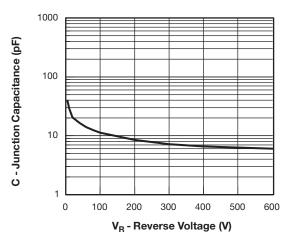


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

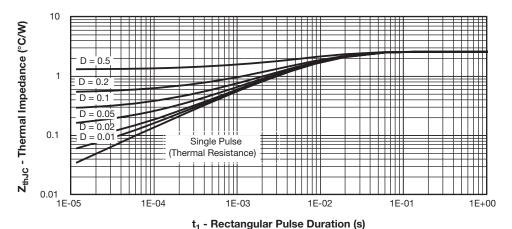


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Vishay Semiconductors

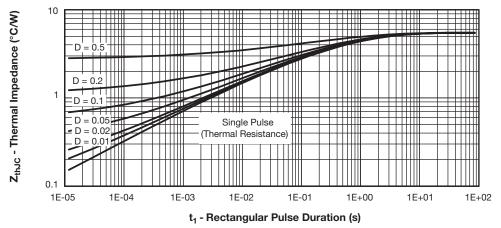


Fig. 5 - Maximum Thermal Impedance ZthJC Characteristics (FULL-PAK)

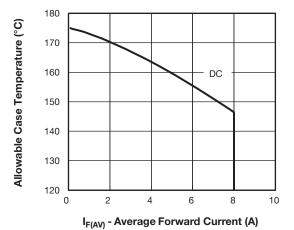


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

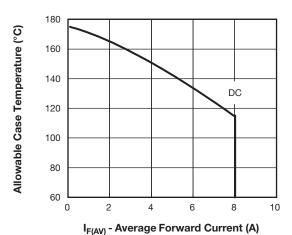
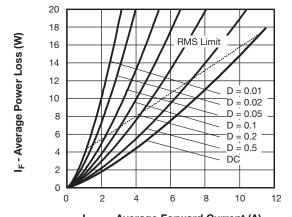


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)



I_{F(AV)} - Average Forward Current (A)
Fig. 8 - Forward Power Loss Characteristics

Vishay Semiconductors

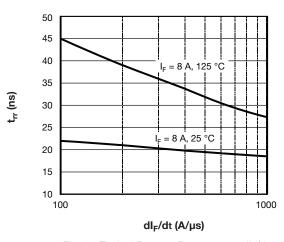


Fig. 9 - Typical Reverse Recovery vs. dl_F/dt

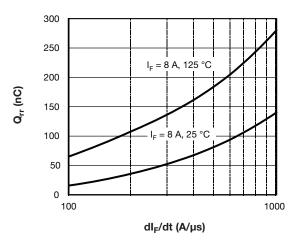


Fig. 10 - Typical Stored Charge vs. dl_F/dt

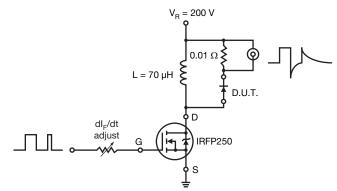
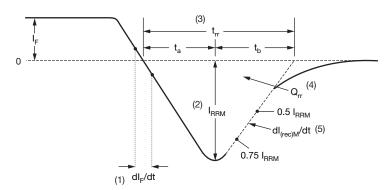


Fig. 11 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

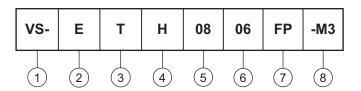
Fig. 12 - Reverse Recovery Waveform and Definitions

VS-ETH0806-M3, VS-ETH0806FP-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

E = Single diode

3 - T = TO-220

H = Hyperfast recovery time

5 - Current code: 08 = 8 A

- Voltage code: 06 = 600 V

7 - • None = TO-220

• FP = FULL-PAK

8 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

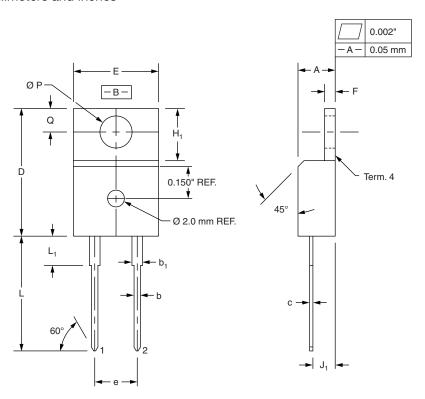
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-ETH0806-M3	50	1000	Antistatic plastic tube			
VS-ETH0806FP-M3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95259				
Dimensions	2L TO-220 FULL-PAK	www.vishay.com/doc?95260			
Part marking information	2L TO-220AC	www.vishay.com/doc?95391			
Part marking information	2L TO-220 FULL-PAK	www.vishay.com/doc?95392			

Vishay Semiconductors

True 2 Pin TO-220

DIMENSIONS in millimeters and inches



SYMBOL -	MILLIM	METERS	INC	HES
STMBOL	MIN.	MAX.	MIN.	MAX.
A	4.32	4.57	0.170	0.180
b	0.71	0.91	0.028	0.036
b ₁	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	14.99	15.49	0.590	0.610
E	10.04	10.41	0.395	0.410
е	5.08	BSC	0.200	BSC
F	1.22	1.37	0.048	0.054
H ₁	5.97	6.47	0.235	0.255
J ₁	2.54	2.79	0.100	0.110
L	13.47	13.97	0.530	0.550
L ₁ (1)	3.31	3.81	0.130	0.150
Ø P	3.79	3.88	0.149	0.153
Q	2.60	2.84	0.102	0.112

Notes

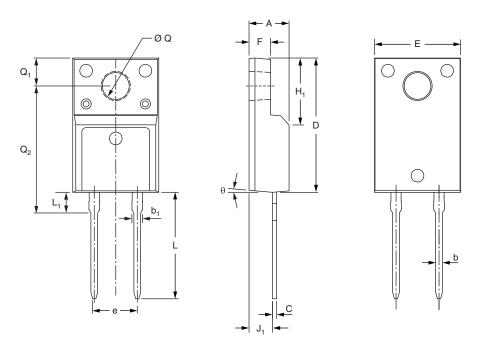
- $^{(1)}$ Lead dimension and finish uncontrolled in L_1
- These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87
- Controling dimension: Inch



Vishay Semiconductors

True 2 Pin TO-220 FULL-PAK

DIMENSIONS in millimeters and inches



CVMDOL	MILLIM	METERS	INCH	IES
SYMBOL	MIN.	MAX.	MIN.	MAX.
A	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b ₁	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
е	5.08 typical		0.200 typical	
F	2.34	2.74	0.092	0.107
H ₁	6.50	6.90	0.256	0.272
J ₁	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L ₁	2.23	2.63	0.088	0.104
ØQ	2.98	3.38	0.117	0.133
Q ₁	3.10	3.50	0.122	0.138
Q_2	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000